Triac (Bidirectional Triode Thyristor)

Selection Guide

Part Number	V _{DRM} (V)	UL-Recognized Component	Package	Packing	
TMA34(I)	400	Yes			
TMA34S-L	400	-	3-pin fully molded SIP with	FO pieces per tube	
TMA36(I)	600	Yes	heatsink mount	50 pieces per tube	
TMA36S-L	600	-			

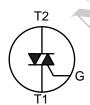
Absolute Maximum Ratings

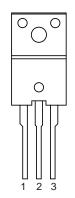
Characteristic	Symbol		Notes	Rating	Units
Dools Donotities Off State Voltage	V_{DRM}	TMA34x		400	V
Peak Repetitive Off-State Voltage		TMA36x	R _{GREF} = ∞	600	V
Dook Non Donatitive Off State Voltage	V _{DSM}	TMA34x	R _{GREF} = ∞	500	V
Peak Non-Repetitive Off-State Voltage		TMA36x		700	V
Isolation Voltage	V _{ISO}	AC RMS app	AC RMS applied for 1 minute between lead and case		
RMS On-State Current	I _{T(RMS)}		50/60 Hz full cycle sine wave, total Conduction angle (α +) + (α -) = 360°, T_C = 109°C		А
	I _{TSM}	f = 60 Hz	Full cycle sine wave, peak value, non-repetitive, initial $T_J = 125^{\circ}\text{C}$	32	А
Surge On-State Current		f = 50 Hz		30	А
I ² t Value for Fusing	l ² t	Value for 50	Value for 50 Hz half cycle sine wave, 1 cycle, I _{TSM} = 30 A		
Peak Gate Current	I _{GM}	f≥50 Hz, du	f ≥ 50 Hz, duty cycle ≤ 10%		А
Peak Gate Power Dissipation	P _{GM}	f ≥ 50 Hz, duty cycle ≤ 10%		3	W
Average Gate Power Dissipation	P _{GM(AV)}	$T_J < T_J(max)$		0.3	W
Junction Temperature	TJ			-40 to 125	°C
Storage Temperature	T _{stg}		-40 to 125	°C	

Thermal Characteristics May require derating at maximum conditions

Characteristic	Symbol	Test Conditions	Value	Units
Package Thermal Resistance (Junction to Case)	$R_{ heta JC}$	For AC	4.5	°C/W

Pin-out Diagram





Terminal List Table

Number	Name	Function
1	T1	Main terminal, gate referenced
2	T2	Main terminal connect to signal side
3	G	Gate control

All performance characteristics given are typical values for circuit or system baseline design only and are at the nominal operating voltage and an ambient temperature, TA, of 25°C, unless otherwise stated.





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ELECTRICAL CHARACTERISTICS

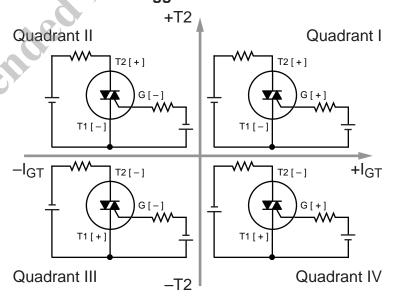
Characteristics	Symbol	Т	Min.	Тур.	Max.	Unit	
Off-State Leakage Current	I _{DRM}	V _D = V _{DRM} , T _J = 125°C, R _{GREF} = ∞ using test circuit 1		ı	ı	2.0	mA
		V _D = V _{DRM} , T _J = 25°C, R _{GREF} = ∞ using test circuit 1		-	-	100	μA
On-State Voltage	V _{TM}	I _T = 4.5 A, T _J = 25°C		_	_	1.5	V
Gate Trigger Voltage	V _{GT}	Quadrant I: T2+, G+	$V_D = 12 \text{ V}, R_L = 20 \Omega, T_J = 25^{\circ}\text{C}$	_	_	1.5	V
		Quadrant II: T2+, G-		-	-	1.5	V
		Quadrant III: T2-, G-		ı		1.5	V
Gate Trigger Current	I _{GT}	Quadrant I: T2+, G+	$V_D = 12 \text{ V}, R_L = 20 \Omega, T_J = 25^{\circ}\text{C}$	_		20	mA
		Quadrant II: T2+, G-		-		20	mA
		Quadrant III: T2-, G-		-	-	20	mA
Gate Non-trigger Voltage	V_{GD}	$V_D = V_{DRM} \times 0.5, R_L = 4 \text{ k}\Omega, T_J = 125^{\circ}\text{C}$ 0.2				V	
Critical Rising Rate of Off-State Voltage during Commutation*	(dv/dt)c	$T_J = 125$ °C, $V_D = 400$ V, $(di/dt)c = -1.5$ A/ms, $I_{TP} = 2$ A		5	_	_	V/µs

^{*}Where I_{TP} is the peak current through T2 to T1.

Test Circuit 1

$R_{GREF} = \infty$ G T1

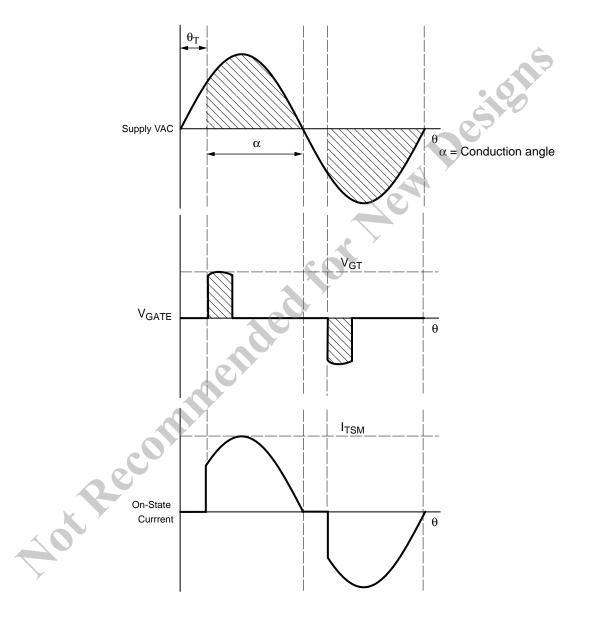
Gate Trigger Characteristics



Polarities referenced to T1



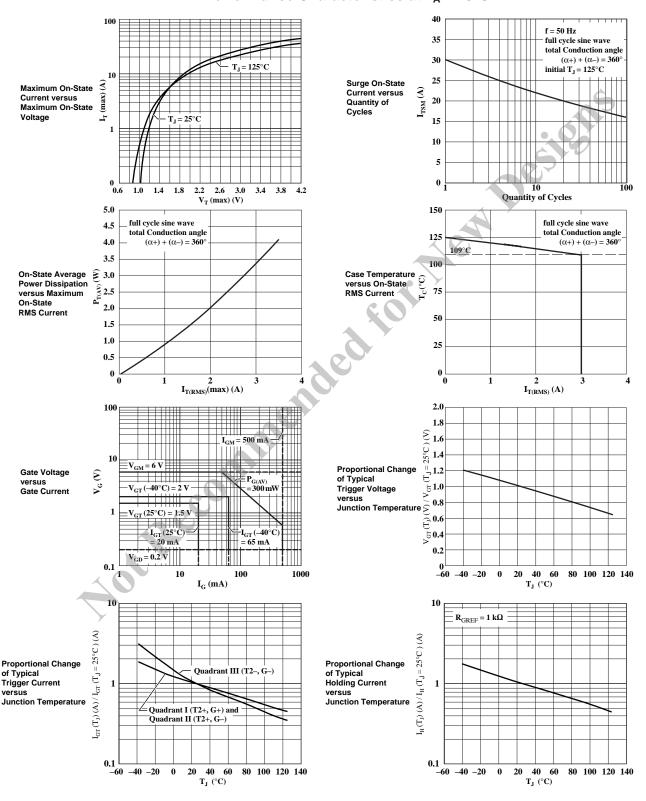
Commutation Timing Diagrams





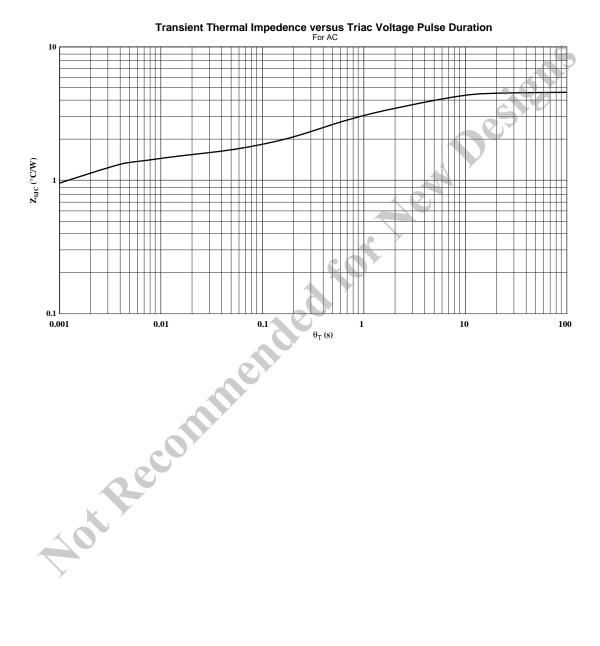


Performance Characteristics at T_A = 25°C





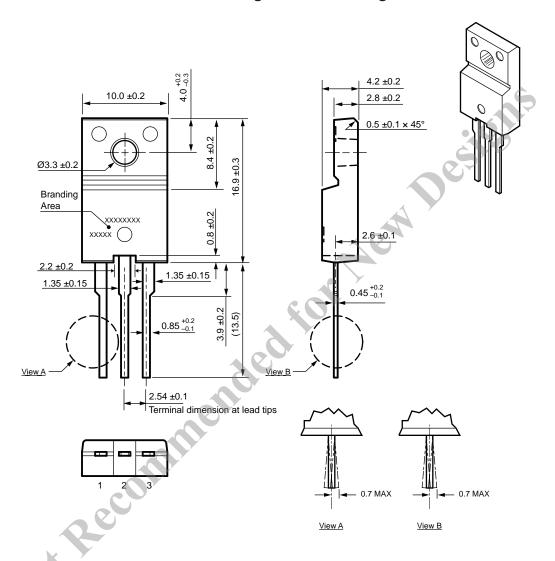








TO-220F Package Outline Drawing



Gate burr: 0.3 mm (max.), mold flash may appear at opposite side

Terminal core material: Cu

Terminal treatment: Ni plating and Pb-free solder dip

Leadform: 600

Package: TO-220F (FM20)

Branding codes (exact appearance at manufacturer discretion):

1st line, type: TMA3x 2nd line, lot: YM

Where: Y is the last digit of the year of manufacture

M is the month (1 to 9, O, N, D)

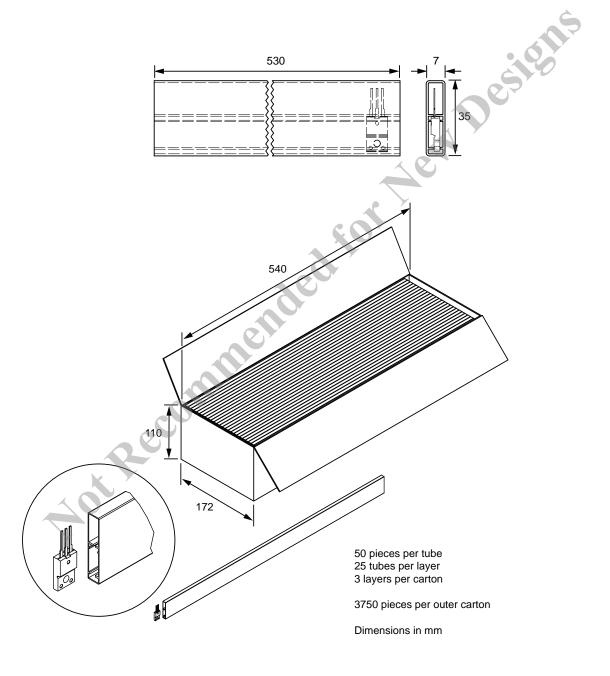






Packing Specification

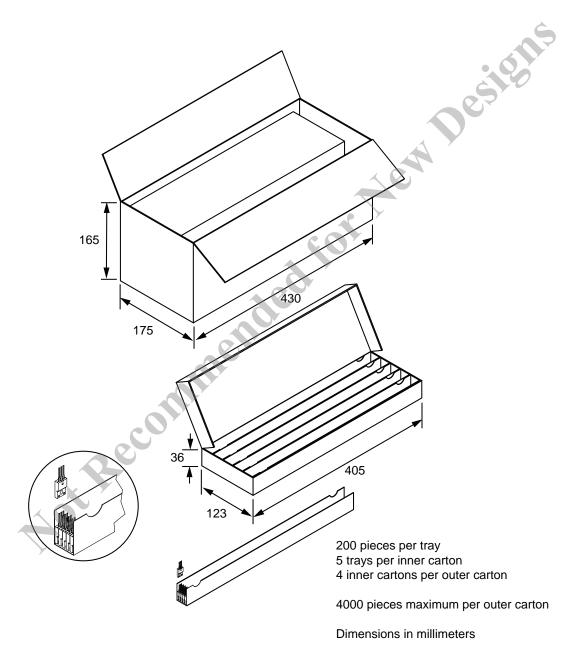
Tube Packing







Bulk Packing







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WARNING — These devices are designed to be operated at lethal voltages and energy levels. Circuit designs that embody these components must conform with applicable safety requirements. Precautions must be taken to prevent accidental contact with power-line potentials. Do not connect grounded test equipment.

The use of an isolation transformer is recommended during circuit development and breadboarding.

Because reliability can be affected adversely by improper storage environments and handling methods, please observe the following cautions.

Cautions for Storage

- Ensure that storage conditions comply with the standard temperature (5°C to 35°C) and the standard relative humidity (around 40 to 75%); avoid storage locations that experience extreme changes in temperature or humidity.
- Avoid locations where dust or harmful gases are present and avoid direct sunlight.
- Reinspect for rust on leads and solderability of products that have been stored for a long time.

Cautions for Testing and Handling

When tests are carried out during inspection testing and other standard test periods, protect the products from power surges from the testing device, shorts between adjacent products, and shorts to the heatsink.

Remarks About Using Silicone Grease with a Heatsink

- When silicone grease is used in mounting this product on a heatsink, it shall be applied evenly and thinly. If more silicone grease than required is applied, it may produce stress.
- Coat the back surface of the product and both surfaces of the insulating plate to improve heat transfer between the product and the heatsink.
- Volatile-type silicone greases may permeate the product and produce cracks after long periods of time, resulting in reduced heat radiation effect, and possibly shortening the lifetime of the product.
- Our recommended silicone greases for heat radiation purposes, which will not cause any adverse effect on the product life, are indicated below:

Type		Suppliers
G746	1	Shin-Etsu Chemical Co., Ltd.
YG6260		Momentive Performance Materials
SC102		Dow Corning Toray Silicone Co., Ltd.

Heatsink Mounting Method

- Torque When Tightening Mounting Screws. Thermal resistance increases when tightening torque is low, and radiation effects are decreased. When the torque is too high, the screw can strip, the heatsink can be deformed, and distortion can arise in the product frame. To avoid these problems, observe the recommended tightening torques for this product package type 0.490 to 0.686 N•m (5 to 7 kgf•cm).
- Diameter of Heatsink Hole: < 4 mm. The deflection of the press mold when making the hole may cause the case material to crack at the joint with the heatsink. Please pay special attention for this effect.

Soldering

 When soldering the products, please be sure to minimize the working time, within the following limits:

260±5°C 10 s 350±5°C 3 s

 Soldering iron should be at a distance of at least 1.5 mm from the body of the products

Electrostatic Discharge

- When handling the products, operator must be grounded. Grounded wrist straps worn should have at least 1 M Ω of resistance to ground to prevent shock hazard.
- Workbenches where the products are handled should be grounded and be provided with conductive table and floor mats.
- When using measuring equipment such as a curve tracer, the equipment should be grounded.
- When soldering the products, the head of soldering irons or the solder bath must be grounded in other to prevent leak voltages generated by them from being applied to the products.
- The products should always be stored and transported in our shipping containers or conductive containers, or be wrapped in aluminum foil.





Triac (Bidirectional Triode Thyristor)

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Anti radioactive ray design is not considered for the products listed herein.

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